

M54512L

4-UNIT 50mA TRANSISTOR ARRAY

DESCRIPTION

The M54512L, 4-channel sink driver, consists of four NPN transistors, and designed for use in medium-current switching applications.

FEATURES

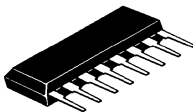
- Output breakdown voltage to 20V
- 50mA output sink current capability
- Wide operating temperature range ($T_a = -20 \sim +75^\circ\text{C}$)

APPLICATION

LED or incandescent display driver

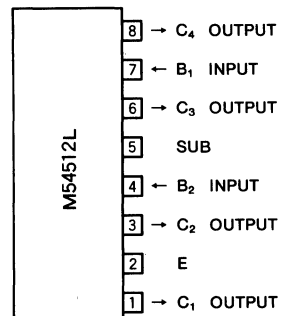
FUNCTION

The M54512L is comprised of four NPN transistors with a $10\text{k}\Omega$ series input resistor, connected to form dual 2-parallel output drivers. All emitters of transistors are connected together to pin 2. The substrate is connected to pin 5 and pin 5 must be tied to the most negative point in the external circuit. The drivers are capable of sinking 50mA and will withstand 20V in the OFF state.



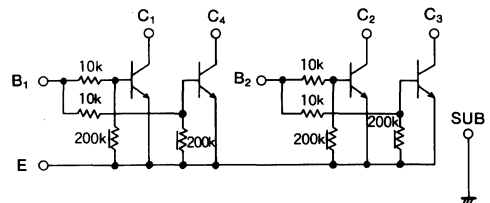
8-pin molded plastic SIL

PIN CONFIGURATION (TOP VIEW)



Outline 8P5

CIRCUIT SCHEMATIC



UNIT : Ω

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Conditions	Limits	Unit
V_{CEO}	Output sustaining voltage	Transistor OFF	20	V
V_{EBO}	Emitter-base sustaining voltage		4	V
I_C	Collector current	Transistor ON	50	mA
V_I	Input voltage		20	V
P_D	Power dissipation	$T_a = 75^\circ\text{C}$	500	mW
T_{opr}	Operating ambient temperature range		$-10 \sim +75$	$^\circ\text{C}$
T_{stg}	Storage temperature range		$-55 \sim +125$	$^\circ\text{C}$

RECOMMENDED OPERATING CONDITIONS ($T_a = 25^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter		Limits			Unit
			Min	Typ	Max	
V_C	Output voltage		0		18	V
I_C	Collector current per channel		0		20	mA
V_{IH}	"H" Input voltage	$I_C = 30\text{mA}$	2			V
V_{IL}	"L" Input voltage				0.2	V

4-UNIT 50mA TRANSISTOR ARRAY

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
$I_{O(leak)}$	Output leakage current	$V_{CE}=20\text{V}$			20	μA
$V_{CE(sat)}$	Output saturation voltage	$I_B=2\text{mA}$			0.1	V
					0.2	V
BV_{EBO}	Emitter-base sustaining voltage	$I_{EBO}=150\mu\text{A}$	4			V
V_i	Input voltage	$I_B=2\text{mA}$		11		V
h_{FE}	DC forward current gain	$V_{CE}=6\text{V}, I_C=20\text{mA}, T_a=25^\circ\text{C}$	60			

TYPICAL CHARACTERISTICS

